Fumiyasu Oba

List of Publications by Year
in descending order

187	14,430	36203 51	19690 117
papers	citations	h-index	g-index

192	192	192	14803
all docs	docs citations	times ranked	citing authors

#	Article	IF	Citations
1	Recommendation of interstitial hydrogen positions in metal oxides. Computational Materials Science, 2022, 203, 111068.	1.4	2
2	Adaptive sampling methods via machine learning for materials screening. Science and Technology of Advanced Materials Methods, 2022, 2, 55-66.	0.4	2
3	Phase variation of ferroelectric <mml:math		

#	Article	IF	Citations
19	Energetics and electronic structure of native point defects in Î±-Ga₂O₃. Applied Physics Express, 2019, 12, 091001.	1.1	35
20	Spin-Glass Magnetic Properties of A-Site Columnar-Ordered Quadruple Perovskites Y2MnGa(Mn4â€“xGax)O12 with 0 â‰¤ x â‰¤ 3. Inorganic Chemistry, 2019, 58, 14830-14841.	1.9	7
21	Achieving non-degenerate Zn3N2 thin films by near room temperature sputtering deposition. Applied Physics Letters, 2019, 115, .	1.5	7
22	Theoretical prediction of strain-induced carrier effective mass modulation in 4H-SiC and GaN. Applied Physics Letters, 2019, 115, .	1.5	13
23	Direct Observation of Magnetization Reversal by Electric Field at Room Temperature in Co-Substituted Bismuth Ferrite Thin Film. Nano Letters, 2019, 19, 1767-1773.	4.5	23
24	Native point defects and carbon clusters in 4H-SiC: A hybrid functional study. Journal of Applied Physics, 2019, 125, .	1.1	55
25	Zinc-based spinel cathode materials for magnesium rechargeable batteries: toward the reversible spinelâ€“rocksalt transition. Journal of Materials Chemistry A, 2019, 7, 12225-12235.	5.2	59
26	One-dimensionally extended oxygen vacancy states in perovskite oxides. Physical Review B, 2019, 99, .	1.1	8
27	Effect of MnO₂ Crystal Structure on Aerobic Oxidation of 5-Hydroxymethylfurfural to 2,5-Furandicarboxylic Acid. Journal of the American Chemical Society, 2019, 141, 890-900.	6.6	299
28	First-principles study of self-trapped holes and acceptor impurities in <mml:math xmlns:mml="http://www.w3.org/1998/Math/MathML"><mml:mrow><mml:msub><mml:mi>Ga</mml:mi><mml:mn>2</mml:mn></mml: mathvariant="normal">O</mml:mi><mml:mn>3</mml:mn></mml:msub></mml:mrow></mml:math> polymorphs. Physical Review Materials, 2019, 3, .	0.9	80
29	<mml:math xmlns:mml="http://www.w3.org/1998/Math/MathML"><mml:mrow><mml:msub><mml:mi>Al</mml:mi><mml:mn>2</mml:mn></mml:m mathvariant="normal">O</mml:mi><mml:mn>3</mml:mn></mml:msub></mml:mrow></mml:math>,<mml:math xmlns:mml="http://www.w3.org/1998/Math/MathML"><mml:mrow><mml:msub><mml:mi>Ga</mml:mi><mml:mn>2</mml:mn></mml: mathvariant="normal">O</mml:mi><mml:mn>3</mml:mn></mml:msub></mml:mrow></mml:math>,<mml:math. Physical Review Materials, 2019, 3, .	0.9	32
30	Stabilization of small polarons in <mml:math xmlns:mml="http://www.w3.org/1998/Math/MathML"><mml:msub><mml:mi>BaTiO</mml:mi><mml:mn>3</mml:mn></mml:msub></m by local distortions. Physical Review Materials, 2019, 3, .	0.9	18
31	Point Defects and <mml:math xmlns:mml="http://www.w3.org/1998/Math/MathML" display="inline"><mml:mi>p</mml:mi></mml:math> -Type Doping in ScN from First Principles. Physical Review Applied, 2018, 9, .	1.5	33
32	Electrically Benign Defect Behavior in Zinc Tin Nitride Revealed from First Principles. Physical Review Applied, 2018, 10, .	1.5	34
33	Heterogeneously Catalyzed Aerobic Oxidation of Sulfides with a BaRuO₃ Nanoperovskite. ACS Applied Materials & Interfaces, 2018, 10, 23792-23801.	4.0	50
34	Fast Diffusion of Multivalent Ions Facilitated by Concerted Interactions in Dualâ€Ion Battery Systems. Advanced Energy Materials, 2018, 8, 1801475.	10.2	59
35	Design and exploration of semiconductors from first principles: A review of recent advances. Applied Physics Express, 2018, 11, 060101.	1.1	109
36	Highâ€Mobility pâ€Type and nâ€Type Copper Nitride Semiconductors by Direct Nitriding Synthesis and In Silico Doping Design. Advanced Materials, 2018, 30, e1801968.	11.1	30

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37	Effects of composition, crystal structure, and surface orientation on band alignment of divalent metal oxides: A first-principles study. Physical Review Materials, 2018, 2, .	0.9	24
38	Strain-engineered Peierls instability in layered perovskite <mml:math xmlns:mml="http://www.w3.org/1998/Math/MathML"><mml:mrow><mml:msub><mml:mi>La</mml:mi><mml:mn>3</mml:mn></mml:r mathvariant="normal">O</mml:mi><mml:mn>7</mml:mn></mml:msub></mml:mrow></mml:math> from first principles. Physical Review Materials, 2018, 2, .	0.9	10
39	Polar metallic behavior of strained antiperovskites ACNi3(A=Mg,Zn,and Cd) from first principles. Physical Review Materials, 2018, 2, .	0.9	14
40	Unusual magnetic structure of the high-pressure synthesized perovskites <mml:math xmlns:mml="http://www.w3.org/1998/Math/MathML"><mml:mrow><mml:mi>A</mml:mi><mml:msub><mml:mi>O</mml:mi></mml:msub></mml:mrow></mml:math>	1.0	17
41	Chemical and Lattice Stability of the Tin Sulfides. Journal of Physical Chemistry C, 2017, 121, 6446-6454.	1.5	73
42	DFT investigation into the underperformance of sulfide materials in photovoltaic applications. Journal of Materials Chemistry A, 2017, 5, 9132-9140.	5.2	19
43	Lattice dynamics of the tin sulphides SnS₂, SnS and Sn₂S₃: vibrational spectra and thermal transport. Physical Chemistry Chemical Physics, 2017, 19, 12452-12465.	1.3	187
44	Metastable cubic tin sulfide: A novel phonon-stable chiral semiconductor. APL Materials, 2017, 5, 036101.	2.2	51
45	Theory of ionization potentials of nonmetallic solids. Physical Review B, 2017, 95, .	1.1	18
46	Band structure diagram paths based on crystallography. Computational Materials Science, 2017, 128, 140-184.	1.4	457
47	Complex Structural Behavior of BiMn₇O₁₂ Quadruple Perovskite. Inorganic Chemistry, 2017, 56, 12272-12281.	1.9	23
48	Perovskite-Type InCoO3 with Low-Spin Co3+: Effect of Inâ€“O Covalency on Structural Stabilization in Comparison with Rare-Earth Series. Inorganic Chemistry, 2017, 56, 11113-11122.	1.9	7
49	Comparison of approximations in density functional theory calculations: Energetics and structure of binary oxides. Physical Review B, 2017, 96, .	1.1	85
50	Carrier-Induced Band-Gap Variation and Point Defects in <mml:math xmlns:mml="http://www.w3.org/1998/Math/MathML" display="inline"><mml:mrow><mml:msub><mml:mrow><mml:mi>Zn</mml:mi></mml:mrow><mml:mrow><mml:mn>3</mml:mn><mml:mn></mml:mn></mml:mrow> mathvariant="normal">N</mml:mi></mml:mrow><mml:mrow><mml:mn>2</mml:mn></mml:mrow></mml:msub></mml:mrow></mml: from First Principles. Physical Review Applied, 2017, 8, .	1.5	28
51	Band alignment of semiconductors and insulators using dielectric-dependent hybrid functionals: Toward high-throughput evaluation. Physical Review B, 2017, 95, .	1.1	59
52	Discovery of a Novel Sn(II)â€Based Oxide Î²â€SnMoO₄ for Daylightâ€Driven Photocatalysis. Advanced Science, 2017, 4, 1600246.	5.6	22
53	Prediction of Fundamental Properties of Semiconductors and Materials Exploration Using First-Principles Calculations. Materia Japan, 2017, 56, 554-559.	0.1	0
54	Predictions of point defect, surface, and interface properties in semiconductors using first-principles calculations. AIP Conference Proceedings, 2016, , .	0.3	1

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55	Electronic Structure and Defect Chemistry of Tin(II) Complex Oxide SnNb₂O₆. Journal of Physical Chemistry C, 2016, 120, 9604-9611.	1.5	25
56	Ligancy-Driven Controlling of Covalency and Metallicity in a Ruthenium Two-Dimensional System. Chemistry of Materials, 2016, 28, 5784-5790.	3.2	3
57	Electronic Structure and Defect Physics of Tin Sulfides: SnS,<mml:math xmlns:mml="http://www.w3.org/1998/Math/MathML" display="inline"><mml:mrow><mml:msub><mml:mrow><mml:mi>Sn</mml:mi></mml:mrow><mml:mrow><mml:mn>2</mml:mn></mml:mrow></mml:msub></mml:mrow></mml:math>S,<mml:math xmlns:mml="http://www.w3.org/1998/Math/MathML" display="inline"><mml:mrow><mml:msub><mml:mrow><mml:mi>Sn</mml:mi></mml:mrow><mml:mrow><mml:mn>3</mml:mn></mml:mrow></mml:msub></mml:mrow></mml:math>S₂, and<mml:math xmlns:mml="http://www.w3.org/1998/Math/MathML" display="inline"><mml:mrow><mml:msub><mml:mrow><mml:mi>Sn</mml:mi></mml:mrow><mml:mrow><mml:mn>2</mml:mn></mml:mrow></mml:msub></mml:mrow></mml:math>S₃. Physical Review Applied, 2016,	1.5	138
58	Discovery of earth-abundant nitride semiconductors by computational screening and high-pressure synthesis. Nature Communications, 2016, 7, 11962.	5.8	208
59	Categorization of surface polarity from a crystallographic approach. Computational Materials Science, 2016, 113, 221-230.	1.4	43
60	LiNbO₃-Type Oxide (Tl_{1â€“x}Sc_x)ScO₃: High-Pressure Synthesis, Crystal Structure, and Electronic Properties. Inorganic Chemistry, 2016, 55, 1940-1945.	1.9	6
61	Screening procedure for structurally and electronically matched contact layers for high-performance solar cells: hybrid perovskites. Journal of Materials Chemistry C, 2016, 4, 1149-1158.	2.7	45
62	Complex Point Defect Structure in Cubic Boron Nitride. Materia Japan, 2016, 55, 609-609.	0.1	0
63	Intercalation and Pushâ€Out Process with Spinelâ€toâ€Rocksalt Transition on Mg Insertion into Spinel Oxides in Magnesium Batteries. Advanced Science, 2015, 2, 1500072.	5.6	153
64	Epitaxial growth of tin(II) niobate with a pyrochlore structure. Journal of Crystal Growth, 2015, 416, 126-129.	0.7	5
65	Toward â€œrocking-chair typeâ€•Mgâ€“Li dual-salt batteries. Journal of Materials Chemistry A, 2015, 3, 10188-10194.	5.2	72
66	Electrostatics-based finite-size corrections for first-principles point defect calculations. Physical Review B, 2014, 89, .	1.1	320
67	Band alignment of semiconductors from density-functional theory and many-body perturbation theory. Physical Review B, 2014, 90, .	1.1	271
68	Ionization Potentials of Solids: The Importance of Vertex Corrections. Physical Review Letters, 2014, 112, 096401.	2.9	184
69	First-principles study of point defects in chalcopyrite<mml:math xmlns:mml="http://www.w3.org/1998/Math/MathML"><mml:msub><mml:mi>ZnSnP</mml:mi><mml:mn>2</mml:mn></mml:msub></mml:math>: Physical Review B, 2014, 90, .	1.1	49
70	Atomic Structure of Luminescent Centers in High-Efficiency Ce-doped w-AlN Single Crystal. Scientific Reports, 2014, 4, 3778.	1.6	43
71	Strong Spinâ€Lattice Coupling Through Oxygen Octahedral Rotation in Divalent Europium Perovskites. Advanced Functional Materials, 2013, 23, 1864-1872.	7.8	41
72	First-principles study of valence band offsets at ZnSnP2/CdS, ZnSnP2/ZnS, and related chalcopyrite/zincblende heterointerfaces. Journal of Applied Physics, 2013, 114, .	1.1	24

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73	Functional Complex Point-Defect Structure in a Huge-Size-Mismatch System. Physical Review Letters, 2013, 110, 065504.	2.9	40
74	Antiâ€ferrodistortiveâ€Like Oxygenâ€Octahedron Rotation Induced by the Oxygen Vacancy in Cubic SrTiO₃. Advanced Materials, 2013, 25, 86-90.	11.1	94
75	Valence band offsets at zinc-blende heterointerfaces with misfit dislocations: A first-principles study. Physical Review B, 2013, 88, .	1.1	15
76	Band offsets of CuInSe<mml:math xmlns:mml="http://www.w3.org/1998/Math/MathML" display="inline"><mml:msub><mml:mrow /><mml:mn>2</mml:mn></mml:msub></mml:math>/CdS and CuInSe<mml:math xmlns:mml="http://www.w3.org/1998/Math/MathML" display="inline"><mml:msub><mml:mrow /><mml:mn>2</mml:mn></mml:msub></mml:math>/ZnS (110) interfaces: A hybrid density functional theory study. Physical Review B, 2013, 88, .	1.1	50
77	Theoretical Photovoltaic Conversion Efficiencies of ZnSnP₂, CdSnP₂, and Zn_{1-x}Cd_xSnP₂Alloys. Applied Physics Express, 2013, 6, 061201.	1.1	39
78	Local environment of silicon in cubic boron nitride. Journal of Applied Physics, 2013, 114, 233502.	1.1	10
79	Site preference of cation vacancies in Mn-doped Ga2O3 with defective spinel structure. Applied Physics Letters, 2012, 101, .	1.5	14
80	Crystal and Electronic Structure and Magnetic Properties of Divalent Europium Perovskite Oxides EuMO₃ (M = Ti, Zr, and Hf): Experimental and First-Principles Approaches. Inorganic Chemistry, 2012, 51, 4560-4567.	1.9	54
81	of CuInSe<mml:math xmlns:mml="http://www.w3.org/1998/Math/MathML" display="inline"><mml:msub><mml:mrow /><mml:mn>2</mml:mn></mml:msub></mml:math>and CuGaSe<mml:math xmlns:mml="http://www.w3.org/1998/Math/MathML"	1.1	70
82	Defect chemistry of a BaZrO3 Î£3 (111) grain boundary by first principles calculations and spaceâ€“charge theory. Physical Chemistry Chemical Physics, 2012, 14, 12339.	1.3	46
83	Ground-state search in multicomponent magnetic systems. Physical Review B, 2012, 85, .	1.1	3
84	First-principles calculations of the phase diagrams and band gaps in CuInSe2-CuGaSe2and CuInSe2-CuAlSe2pseudobinary systems. Physical Review B, 2012, 85, .	1.1	32
85	Antiferromagnetic superexchange via <mml:math xmlns:mml="http://www.w3.org/1998/Math/MathML" display="inline"><mml:mrow><mml:mn>3</mml:mn><mml:mi>d</mml:mi></mml:mrow></mml:math>states of titanium in EuTiO<mml:math xmlns:mml="http://www.w3.org/1998/Math/MathML" display="inline"><mml:mrow><mml:msub><mml:mrow /><mml:mrow><mml:mn>3</mml:mn></mml:mrow></mml:msub></mml:mrow></mml:math>as seen from hybrid Hartree-Fock density functional calculations. Physical Review B, 2011, 83, .	1.1	104
86	Electronic and structural properties of the oxygen vacancy in BaTiO3. Applied Physics Letters, 2011, 98, .	1.5	61
87	Point defects in ZnO: an approach from first principles. Science and Technology of Advanced Materials, 2011, 12, 034302.	2.8	279
88	Hybrid density functional study of oxygen vacancies in KTaO3and NaTaO3. Physical Review B, 2011, 83, .	1.1	26
89	Atomistic structure and energetics of interface between Mn-doped Î³-Ga2O3 and MgAl2O4. Journal of Materials Science, 2011, 46, 4169-4175.	1.7	12
90	Epitaxial Growth and Characterization of Rocksalt ZnO Thin Films with Low-Level NiO Alloying. Japanese Journal of Applied Physics, 2011, 50, 075503.	0.8	3

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91	Epitaxial growth of Mn-doped Î³-Ga₂O₃ on spinel substrate. Journal of Materials Research, 2011, 26, 578-583.	1.2	46
92	Non-Fermi-Liquid Behavior on an Iron-Based Itinerant Electron Magnet Fe₃Mo₃N. Journal of the Physical Society of Japan, 2010, 79, 043701.	0.7	17
93	Doping of hexagonal boron nitride via intercalation: A theoretical prediction. Physical Review B, 2010, 81, .	1.1	61
94	Phase relationships and structures of inorganic crystals by a combination of the cluster expansion method and first principles calculations. Journal of Physics Condensed Matter, 2010, 22, 384207.	0.7	1
95	Classification of spinel structures based on first-principles cluster expansion analysis. Physical Review B, 2010, 81, .	1.1	38
96	Thermodynamics and structures of oxide crystals by a systematic set of first principles calculations. Journal of Materials Chemistry, 2010, 20, 10335.	6.7	7
97	Native defects in oxide semiconductors: a density functional approach. Journal of Physics Condensed Matter, 2010, 22, 384211.	0.7	47
98	Variable anisotropy of ionic conduction in lithium nitride: Effect of duplex-charge transfer. Physical Review B, 2009, 80, .	1.1	6
99	First-principles study of defect-induced potentials in<mml:math xmlns:mml="http://www.w3.org/1998/Math/MathML" display="inline"><mml:mrow><mml:msub><mml:mrow><mml:mtext>Ca</mml:mtext></mml:mrow><mml:mn>2</mml:mn></mml:msu Physical Review B, 2009, 80, .	1.1	5
100	Role of Ti Antisitelike Defects in<mml:math xmlns:mml="http://www.w3.org/1998/Math/MathML" display="inline"><mml:msub><mml:mi>SrTiO</mml:mi><mml:mn>3</mml:mn></mml:msub></mml:math>. Physical Review Letters, 2009, 103, 185502.	2.9	109
101	²⁷Al NMR Chemical Shifts in Oxide Crystals: A First-Principles Study. Journal of Physical Chemistry C, 2009, 113, 3869-3873.	1.5	53
102	First Principles Thermodynamics Calculations of Atomic Scale Modifications. Materia Japan, 2009, 48, 299-302.	0.1	0
103	First-principles investigation of R2O3(ZnO)3 (R=Al, Ga, and In) in homologous series of compounds. Journal of Solid State Chemistry, 2008, 181, 137-142.	1.4	14
104	Defect energetics in ZnO: A hybrid Hartree-Fock density functional study. Physical Review B, 2008, 77, .	1.1	655
105	First-principles study of native defects and lanthanum impurities in<mml:math xmlns:mml="http://www.w3.org/1998/Math/MathML" display="inline"><mml:mrow><mml:msub><mml:mrow><mml:mtext>NaTaO</mml:mtext></mml:mrow><mml:mn>3</mml:mn></mml:mr Physical Review B, 2008, 78, .	1.1	58
106	Structure and Stability of a Homologous Series of Tin Oxides. Physical Review Letters, 2008, 100, 045702.	2.9	146
107	First-principles calculations of the ferroelastic transition between rutile-type and<mml:math xmlns:mml="http://www.w3.org/1998/Math/MathML" display="inline"><mml:mrow><mml:msub><mml:mrow><mml:mtext>CaCl</mml:mtext></mml:mrow><mml:mn>2</mml:mn></mml:msub></mml:mrow></mml:math>-type<mml:math xmlns:mml="http://www.w3.org/1998/Math/MathML" display="inline"><mml:mrow><mml:msub><mml:mrow><mml:mtext>SiO</mml:mtext></mml:mrow><mml:mn>2</mml:mn></mml:msub></mml:mrow></mml:math> high pressures. Physical Review B, 2008, 78, .	1.1	4,498
108	First-principles approach to chemical diffusion of lithium atoms in a graphite intercalation compound. Physical Review B, 2008, 78, .	1.1	210

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109	First principles calculations for modern ceramic science and engineering. Journal of Physics Condensed Matter, 2008, 20, 064215.	0.7	4
110	First Principles Calculations of Advanced Nitrides, Oxides and Alloys. Key Engineering Materials, 2008, 403, 73-76.	0.4	0
111	Effects of crystal structure on Co-<mml:math xmlns:mml="http://www.w3.org/1998/Math/MathML" display="inline"><mml:mrow><mml:msub><mml:mi>L</mml:mi><mml:mrow><mml:mn>2</mml:mn><mml:mo>,</mml:mo><mml:m absorption near-edge structure and electron-energy-loss near-edge structure of trivalent cobalt oxides. Physical Review B, 2008, 77, .	1.1	37
112	Transition pathway of<mml:math xmlns:mml="http://www.w3.org/1998/Math/MathML" display="inline"><mml:mrow><mml:mi mathvariant="normal">C</mml:mi><mml:msub><mml:mi mathvariant="normal">O</mml:mi><mml:mn>2</mml:mn></mml:msub></mml:mrow></mml:math>crystals under high pressures. Physical Review B, 2008, 77, .	1.1	65
113	First-principles-based phase diagram of the cubic BNC ternary system. Physical Review B, 2008, 77, .	1.1	36
114	First Principles Calculation of CO and H₂ Adsorption on Strained Pt Surface. Materials Transactions, 2008, 49, 2484-2490.	0.4	6
115	Atomic structures of supersaturated ZnOâ€“Al2O3 solid solutions. Journal of Applied Physics, 2008, 103, 014309.	1.1	68
116	First-principles study of defect equilibria in lithium zinc nitride. Journal of Physics Condensed Matter, 2007, 19, 046201.	0.7	6
117	Microstructure of Mn-doped Î³-Ga2O3 epitaxial film on sapphire (0001) with room temperature ferromagnetism. Journal of Applied Physics, 2007, 101, 063526.	1.1	46
118	Awaking of ferromagnetism in GaMnN through control of Mn valence. Applied Physics Letters, 2007, 90, 012504.	1.5	15
119	Ordering and segregation of aCu75Pt25(111)surface: A first-principles cluster expansion study. Physical Review B, 2007, 76, .	1.1	31
120	Atomic-Scale Processes of Grain-Boundary Faceting in a Zirconia Bicrystal. Materials Science Forum, 2007, 558-559, 955-958.	0.3	0
121	Structures and energetics of Ga₂O₃polymorphs. Journal of Physics Condensed Matter, 2007, 19, 346211.	0.7	253
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123	Coexistence of Mn2+and Mn3+in ferromagnetic GaMnN. Journal of Physics Condensed Matter, 2006, 18, 4615-4621.	0.7	43
124	First-principles study of bulk ordering and surface segregation in Pt-Rh binary alloys. Physical Review B, 2006, 74, .	1.1	67
125	First-principles calculations of native defects in tin monoxide. Physical Review B, 2006, 74, .	1.1	276
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127	Debye temperature and stiffness of carbon and boron nitride polymorphs from first principles calculations. Physical Review B, 2006, 73, .	1.1	218
128	Carbon supersaturation due to paraequilibrium carburization: Stainless steels with greatly improved mechanical properties. Acta Materialia, 2006, 54, 1597-1606.	3.8	161
129	Room temperature ferromagnetism in Mn-doped Î³-Ga2O3 with spinel structure. Applied Physics Letters, 2006, 89, 181903.	1.5	97
130	First-principles study of cation disordering inMgAl2O4spinel with cluster expansion and Monte Carlo simulation. Physical Review B, 2006, 73, .	1.1	47
131	Structure Units of <I>Σ</I>9 Zirconia Grain Boundary. Materia Japan, 2006, 45, 842-842.	0.1	0
132	Structure of Oxide Interfaces Viewed at An Atomistic and Electronic Level. Materia Japan, 2005, 44, 687-690.	0.1	0
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135	Effect of boundary plane on the atomic structure of [0001] Î£ 7 tilt grain boundaries in ZnO. Journal of Materials Science, 2005, 40, 3067-3074.	1.7	13
136	Grain Boundary Dependence of Dopant Segregation and Electrical Property in ZnO. Materia Japan, 2005, 44, 965-965.	0.1	0
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138	Identification of Mg Vacancy in MgO by Positron Lifetime Measurements and First-Principles Calculations. Defect and Diffusion Forum, 2005, 242-244, 1-8.	0.4	1
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140	General Rule for Displacive Phase Transitions in Perovskite Compounds Revisited by First Principles Calculations. Physical Review Letters, 2005, 94, 035502.	2.9	43
141	Arrangement of multiple structural units in a [0001]Î£49tilt grain boundary in ZnO. Physical Review B, 2005, 72, .	1.1	31
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143	Epitaxial Electrodeposition of High-Aspect-Ratio Cu2O(110) Nanostructures on InP(111). Chemistry of Materials, 2005, 17, 725-729.	3.2	74
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145	Interfacial structures of Y123 and Nd123 films formed on MgO(001) substrates by liquid phase epitaxy. Journal of Materials Research, 2004, 19, 2674-2682.	1.2	10
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